

650V 40A Field Stop Trench IGBT

V _{CES}	650V
I _{C(100°C)}	40A
V _{CE(sat) (Typ.)}	1.6V
P_D	234W

● Features

- 1) Low Collector Emitter Saturation Voltage
- 2) High Speed Switching
- 3) Low Switching Loss & Soft Switching
- 4) Pb free Lead Plating; RoHS Compliant

Applications

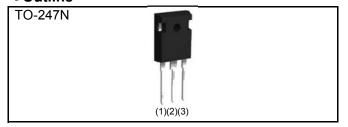
PFC

UPS

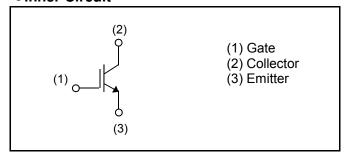
Power Conditioner

ΙH

Outline



●Inner Circuit



Packaging Specifications

	Packaging	Tube	
		Reel Size (mm)	-
١,	Typo	Tape Width (mm)	-
	Гуре	Basic Ordering Unit (pcs)	450
		Packing code	C11
		Marking	RGTH80TS65

● Absolute Maximum Ratings (at T_C = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V _{CES}	650	V
Gate - Emitter Voltage		V_{GES}	±30	V
Callactor Current	T _C = 25°C	I _C	70	А
Collector Current	T _C = 100°C	I _C	40	А
Pulsed Collector Current	ulsed Collector Current		160	А
Dower Dissipation	T _C = 25°C	P _D	234	W
Power Dissipation	T _C = 100°C	P _D	117	W
Operating Junction Temperature		T _j	-40 to +175	°C
Storage Temperature		T _{stg}	-55 to +175	°C

^{*1} Pulse width limited by T_{jmax.}

●Thermal Resistance

Parameter	Symbol	Values			Unit
raiametei		Min.	Тур.	Max.	Offic
Thermal Resistance IGBT Junction - Case	$R_{\theta(j-c)}$	-	-	0.64	°C/W

ullet IGBT Electrical Characteristics (at $T_j = 25$ °C unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
r ai ai i i e te i	Syllibol		Min.	Тур.	Max.	Offic
Collector - Emitter Breakdown Voltage	BV _{CES}	$I_{C} = 10 \mu A, V_{GE} = 0 V$	650	ı	ı	V
Collector Cut - off Current	I _{CES}	V _{CE} = 650V, V _{GE} = 0V	1	1	10	μΑ
Gate - Emitter Leakage Current	I _{GES}	$V_{GE} = \pm 30V, V_{CE} = 0V$	1	-	±200	nA
Gate - Emitter Threshold Voltage	$V_{\text{GE(th)}}$	$V_{CE} = 5V, I_{C} = 27.6 \text{mA}$	4.5	5.5	6.5	V
Collector - Emitter Saturation		I _C = 40A, V _{GE} = 15V				
Voltage	$V_{CE(sat)}$	$T_j = 25^{\circ}C$	-	1.6	2.1	V
		T _j = 175°C	-	2.1	-	

●IGBT Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Darameter	Symbol	Conditions	Values			Lloit
Parameter			Min.	Тур.	Max.	Unit
Input Capacitance	C _{ies}	V _{CE} = 30V	-	2210	-	
Output Capacitance	C _{oes}	V _{GE} = 0V	-	85	-	pF
Reverse Transfer Capacitance	C _{res}	f = 1MHz	-	35	-	
Total Gate Charge	Q _g	V _{CE} = 300V	-	79	-	
Gate - Emitter Charge	Q_{ge}	I _C = 40A	-	21	-	nC
Gate - Collector Charge	Q_{gc}	V _{GE} = 15V	-	29	-	
Turn - on Delay Time	t _{d(on)}	I _C = 40A, V _{CC} = 400V	-	34	-	
Rise Time	t _r	$V_{GE} = 15V, R_G = 10\Omega$	-	50	-	
Turn - off Delay Time	t _{d(off)}	T _j = 25°C	-	120	-	ns
Fall Time	t _f	Inductive Load	-	47	-	
Turn - on Delay Time	t _{d(on)}	I _C = 40A, V _{CC} = 400V	-	34	-	
Rise Time	t _r	$V_{GE} = 15V, R_{G} = 10\Omega$	-	50	-	no
Turn - off Delay Time	$t_{d(off)}$	T _j = 175°C	-	135	-	ns
Fall Time	t _f	Inductive Load	-	59	-	
		I _C = 160A, V _{CC} = 520V				
Reverse Bias Safe Operating Area	RBSOA	$V_P = 650V, V_{GE} = 15V$	FULL SQUARE			-
		$R_G = 60\Omega, T_j = 175^{\circ}C$				

Electrical Characteristic Curves

Fig.1 Power Dissipation vs. Case Temperature

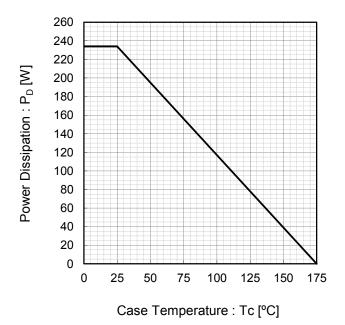


Fig.2 Collector Current vs. Case Temperature

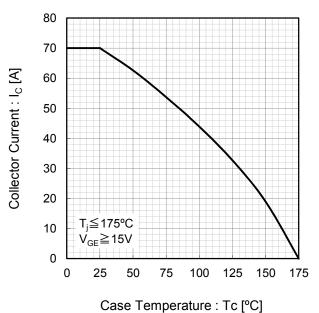
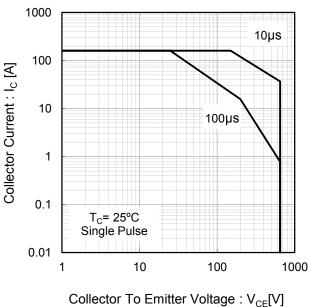
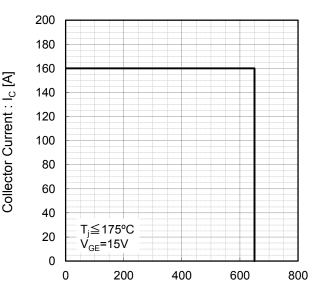


Fig.3 Forward Bias Safe Operating Area



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Fig.4 Reverse Bias Safe Operating Area



Collector To Emitter Voltage : V_{CE}[V]

Electrical Characteristic Curves

Fig.5 Typical Output Characteristics

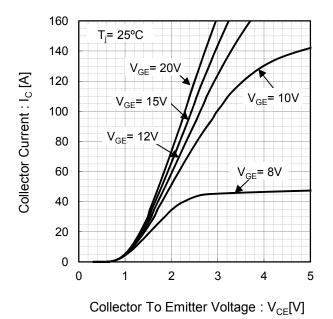
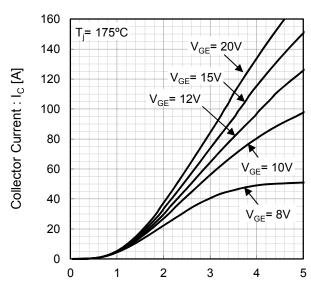


Fig.6 Typical Output Characteristics



Collector To Emitter Voltage : $V_{CE}[V]$

Fig.7 Typical Transfer Characteristics

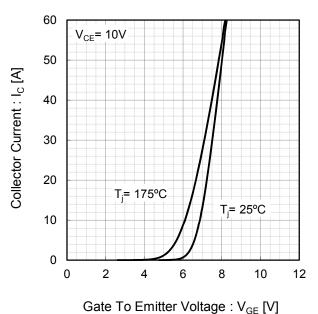
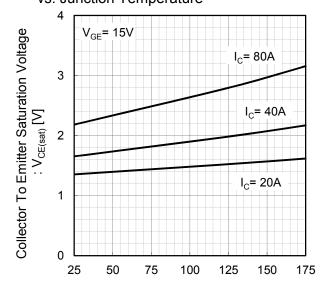


Fig.8 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature



Electrical Characteristic Curves

Fig.9 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage

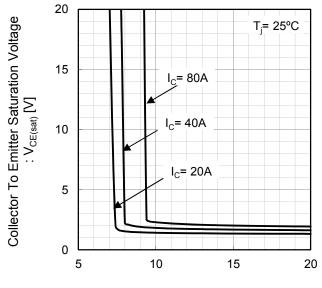
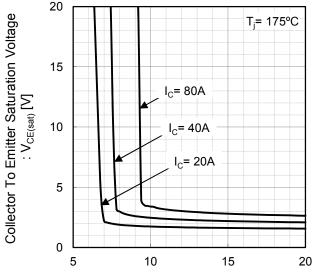


Fig.10 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage



Gate To Emitter Voltage : V_{GE} [V]

Gate To Emitter Voltage : $V_{GE}[V]$

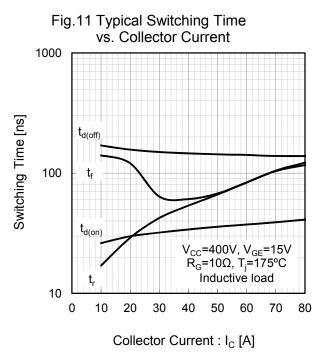
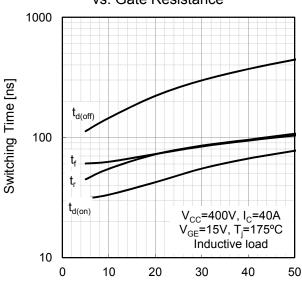


Fig.12 Typical Switching Time vs. Gate Resistance



Gate Resistance : $R_G[\Omega]$

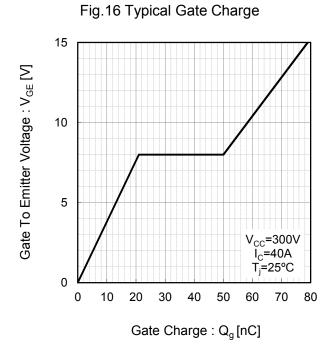
• Electrical Characteristic Curves

Fig.13 Typical Switching Energy Losses vs. Collector Current 10 Switching Energy Losses [mJ] 1 E_{off} 0.1 V_{CC} =400V, V_{GE} =15V R_{G} =10 Ω , T_{j} =175°C Inductive load 0.01 0 10 20 30 50 60 70 80 Collector Current : I_C [A]

vs. Gate Resistance 10 Switching Energy Losses [mJ] $\mathsf{E}_{\mathsf{off}}$ 1 E_{on} 0.1 V_{CC}=400V, I_C=40A V_{GE}=15V, T_j=175°C Inductive load 0.01 0 10 20 30 40 50 Gate Resistance : $R_G[\Omega]$

Fig.14 Typical Switching Energy Losses

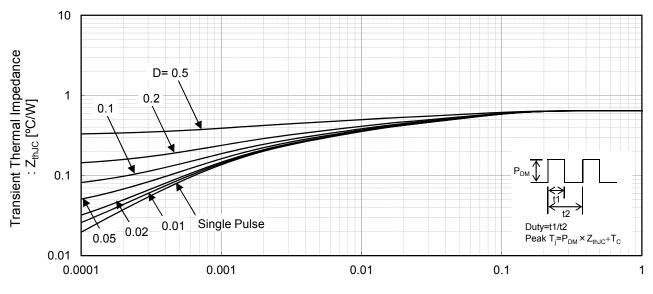
Fig.15 Typical Capacitance vs. Collector To Emitter Voltage 10000 Cies 1000 Capacitance [pF] Coes 100 Cres 10 f=1MHz V_{GE}=0V -25°C 0.01 0.1 1 10 100 Collector To Emitter Voltage : V_{CE}[V]



ROHM

• Electrical Characteristic Curves

Fig.17 IGBT Transient Thermal Impedance



Pulse Width: t1[s]

●Inductive Load Switching Circuit and Waveform

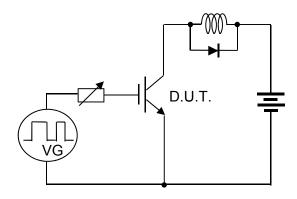


Fig.18 Inductive Load Circuit

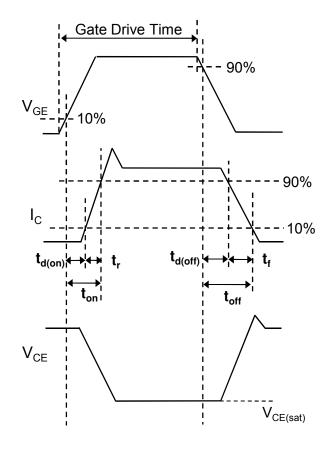


Fig.19 Inductive Load Waveform

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